

UNISONIC TECHNOLOGIES CO., LTD

Preliminary

170mA, 100V N-CHANNEL POWER MOSFET

DESCRIPTION

The UTC $\mbox{BSS123}$ is an N-channel mode Power MOSFET, it uses UTC's advanced technology to provide the customers with low $C_{\mbox{RSS}}.$

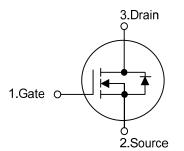
The UTC **BSS123** is suitable for Automotive and Other Applications Requiring.

FEATURES

* $R_{DS(on)} \le 6.0\Omega$ @ V_{GS} =10V, I_D =100mA

* Low C_{RSS}

SYMBOL



3 2 1 2 SOT-23 (EIAJ SC-59)

ORDERING INFORMATION

Ordering Number		Package	Pin Assignment			Packing	
Lead Free	Halogen Free	Fackage	1	2	3	Facking	
BSS123L-AE3-R	SOT-23	G	S	D	Tape Reel		
Note: Pin Assignment:	Note: Pin Assignment: G: Gate S: Source D: Drain						
BSS123G-AE3-R (1)Packing Type (2)Package Type (3)Green Package (3) G: Halogen Free and Lead Free, L: Lead Free						.ead Free	
MARKING							
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■ ABSOLUTE MAXIMUM RATINGS

PARAMETER		SYMBOL	RATINGS	UNIT	
Drain-Source Voltage		V _{DSS}	100	V	
	Continuous	V _{GSS}	±20	V	
Gate-Source Voltage	Non-Repetitive	V _{GSM}	±40	Vpk	
Drain Current	Continuous (Note 1)	I _D	0.17	А	
Drain Current	Pulsed (Note 2)	I _{DM}	0.68	А	
Devuer Dissignation	T _A =25°C (Note 3)	Р	225	mW	
Power Dissipation	Derate above 25°C	PD	1.8	mW/°C	
Junction Temperature		TJ	-55 ~ +150	°C	
Storage Temperature Range		T _{STG}	-55~ +150	°C	

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

THERMAL CHARACTERISTICS

PARAMETER	SYMBOL	RATINGS	UNIT	
Junction to Ambient	θ_{JA}	556	°C/W	

■ ELECTRICAL CHARACTERISTICS (T_A=25°C, unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT			
OFF CHARACTERISTICS								
BV _{DSS}	I _D =250µA, V _{GS} =0V	100			V			
I _{DSS}	V _{DS} =100V, V _{GS} =0V, T _J =25°C			15	μA			
	V _{DS} =100V, V _{GS} =0V, T _J =125°C			60	μA			
I _{GSS}	I _{GSS} V _{GS} =+20V, V _{DS} =0V			±100	nA			
ON CHARACTERISTICS								
V _{GS(TH)}	V _{DS} =V _{GS} , I _D =1mA	0.6		2.0	V			
R _{DS(ON)}	V _{GS} =10V, I _D =100mA			6.0	Ω			
DYNAMIC PARAMETERS								
C _{ISS}			20		pF			
C _{OSS}	V _{GS} =0V, V _{DS} =25V, f=1.0MHz		9		pF			
C _{RSS}	7		4		pF			
SWITCHING PARAMETERS								
t _{D(ON)}	V_{CC} =30V, I _C =0.28A, V _{GS} =10V,		20		ns			
t _{D(OFF)}	R_{GS} =50 Ω		40		ns			
SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS								
V _{SD}	I _D =0.34A, V _{GS} =0V			1.3	V			
	BV _{DSS} I _{DSS} I _{GSS} V _{GS(TH)} R _{DS(ON)} C _{ISS} C _{OSS} C _{RSS} t _{D(ON)} t _{D(OFF)} CHARACTER	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	$\begin{array}{c c c c c c c c c c c c c c c c c c c $			

Notes: 1. The Power Dissipation of the package may result in a lower continuous drain current.

2. Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2.0%.

3. FR-5=1.0×0.75×0.062 in.



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